# onsemi

# **Complementary Silicon High-Power Transistors**

## 2N3055AG (NPN), MJ15015G (NPN), MJ15016G (PNP)

These PowerBase complementary transistors are designed for high power audio, stepping motor and other linear applications. These devices can also be used in power switching circuits such as relay or solenoid drivers, dc–to–dc converters, inverters, or for inductive loads requiring higher safe operating area than the 2N3055.

## Features

• High Current-Gain - Bandwidth

MAXIMUM RATINGS (Note 1)

- Safe Operating Area
- These Devices are Pb-Free and are RoHS Compliant\*

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage 2N3055AG MJ15015G, MJ15016G	V <sub>CEO</sub>	60 120	Vdc	
Collector–Base Voltage 2N3055AG MJ15015G, MJ15016G	V <sub>CBO</sub>	100 200	Vdc	
Collector–Emitter Voltage Base Reversed Biased 2N3055AG MJ15015G, MJ15016G	V <sub>CEV</sub>	100 200	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	7.0	Vdc	
Collector Current – Continuous	۱ <sub>C</sub>	15	Adc	
Base Current	Ι <sub>Β</sub>	7.0	Adc	
Total Device Dissipation @ T <sub>C</sub> = 25°C 2N3055AG MJ15015G, MJ15016G Derate above 25°C 2N3055AG MJ15015G, MJ15016G	P <sub>D</sub>	115 180 0.65 1.03	W W W/°C W/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Indicates JEDEC Registered Data. (2N3055A)

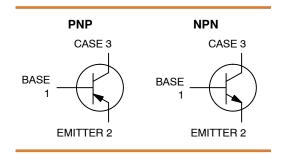
#### THERMAL CHARACTERISTICS

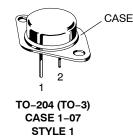
Characteristics	Symbol	Max	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.52	0.98	°C/W

\*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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## 15 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60, 120 VOLTS – 115, 180 WATTS





#### MARKING DIAGRAMS $\cap$ $\cap$ 2N3055AG MJ1501xG AYWW AYWW MEX MFX Ο $\bigcirc$ 2N3055A = Device Code MJ1501x = Device Code x = 5 or 6 G = Pb-Free Package А = Assembly Location Y Year = WW Work Week = MEX Country of Origin

## ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

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## 2N3055AG (NPN), MJ15015G (NPN), MJ15016G (PNP)

## **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS (Note 2)					
Collector–Emitter Sustaining Voltage (Note 3) ( $I_C = 200 \text{ mAdc}, I_B = 0$ )	2N3055AG MJ15015G, MJ15016G	V <sub>CEO(sus)</sub>	60 120		Vdc
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>BE(off)</sub> = 0 Vdc) (V <sub>CE</sub> = 60 Vdc, V <sub>BE(off)</sub> = 0 Vdc)	2N3055AG MJ15015G, MJ15016G	I <sub>CEO</sub>	-	0.7 0.1	mAdc
Collector Cutoff Current (Note 3) (V <sub>CEV</sub> = Rated Value, V <sub>BE(off)</sub> = 1.5 Vdc)	2N3055AG MJ15015G, MJ15016G	I <sub>CEV</sub>	-	5.0 1.0	mAdc
Collector Cutoff Current ( $V_{CEV}$ = Rated Value, $V_{BE(off)}$ = 1.5 Vdc, $T_{C}$ = 150°C)	2N3055AG MJ15015G, MJ15016G	I <sub>CEV</sub>	- -	30 6.0	mAdc
Emitter Cutoff Current ( $V_{EB} = 7.0 \text{ Vdc}, I_C = 0$ )	2N3055AG MJ15015G, MJ15016G	I <sub>EBO</sub>	-	5.0 0.2	mAdc
SECOND BREAKDOWN (Note 3)					
Second Breakdown Collector Current with Base F (t = 0.5 s non-repetitive) (V <sub>CE</sub> = 60 Vdc)	Forward Biased 2N3055AG MJ15015G, MJ15016G	I <sub>S/b</sub>	1.95 3.0		Adc
ON CHARACTERISTICS (Note 2 and 3)					
DC Current Gain (I <sub>C</sub> = 4.0 Adc, V <sub>CE</sub> = 2.0 Vdc) (I <sub>C</sub> = 4.0 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 10 Adc, V <sub>CE</sub> = 4.0 Vdc)		h <sub>FE</sub>	10 20 5.0	70 70 -	-
Collector-Emitter Saturation Voltage ( $I_C = 4.0$ Adc, $I_B = 400$ mAdc) ( $I_C = 10$ Adc, $I_B = 3.3$ Adc) ( $I_C = 15$ Adc, $I_B = 7.0$ Adc)		V <sub>CE(sat)</sub>	- - -	1.1 3.0 5.0	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 4.0 Adc, V <sub>CE</sub> = 4.0 Vdc)		V <sub>BE(on)</sub>	0.7	1.8	Vdc
DYNAMIC CHARACTERISTICS (Note 3)		•		•	•
Current–Gain – Bandwidth Product ( $I_C = 1.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}, f = 1.0 \text{ MHz}$ )	2N3055AG, MJ15015G MJ15016G	f <sub>T</sub>	0.8 2.2	6.0 18	MHz
Output Capacitance ( $V_{CB}$ = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>ob</sub>	60	600	pF
SWITCHING CHARACTERISTICS (2N3055AG o	nly) (Note 3)				
RESISTIVE LOAD					
Delay Time		t <sub>d</sub>	-	0.5	μs
Rise Time	(V <sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 4.0 Adc, I <sub>B1</sub> = I <sub>B2</sub> = 0.4 Adc,	t <sub>r</sub>	-	4.0	μs
Storage Time	$t_p = 25 \ \mu s \ Duty \ Cycle \le 2\%$	t <sub>s</sub>	_	3.0	μs
Fall Time		t <sub>f</sub>	_	6.0	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2%.
Indicates JEDEC Registered Data. (2N3055A)

## 2N3055AG (NPN), MJ15015G (NPN), MJ15016G (PNP)

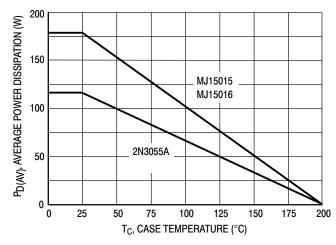
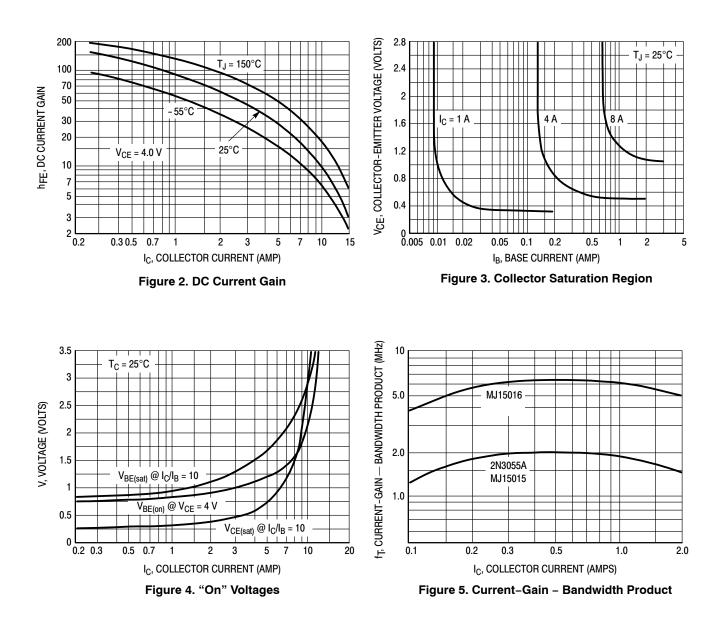


Figure 1. Power Derating



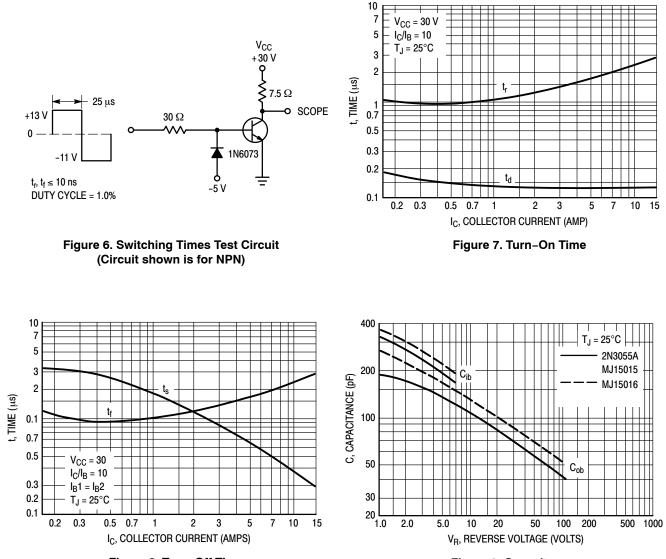
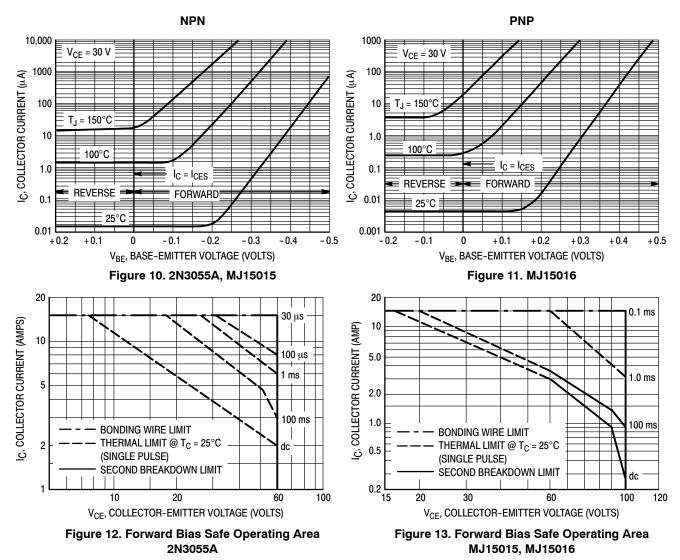


Figure 8. Turn-Off Times

Figure 9. Capacitances

## 2N3055AG (NPN), MJ15015G (NPN), MJ15016G (PNP)

## **COLLECTOR CUT-OFF REGION**



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe Operating area curves indicate  $I_C$  –  $V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 12 and 13 is based on  $T_C = 25^{\circ}C$ ;  $T_{J(pk)}$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated for temperature according to Figure 1.

Device	Package	Shipping
2N3055AG	TO-204 (Pb-Free)	100 Units / Tray
MJ15015G	TO–204 (Pb–Free)	100 Units / Tray
MJ15016G	TO-204 (Pb-Free)	100 Units / Tray

#### **ORDERING INFORMATION**

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



DIMENSIONS			
SCALE 1:1	TO–204 (TO–3) CASE 1–07 ISSUE Z	)	DATE 05/18/1988
$ \begin{array}{c}                                     $	$ \begin{array}{c}                                     $	NOTES: 1. DIMENSIONING AND TC Y14.5M, 1982. 2. CONTROLLING DIMENS 3. ALL RULES AND NOTES REFERENCED TO-204A MIN MAX A 1.550 REF B 1.050 C 0.250 0.335 D 0.038 0.043 E 0.055 0.070 G 0.430 BSC H 0.215 BSC K 0.440 0.480 L 0.665 BSC N 0.830 Q 0.151 0.165 U 1.187 BSC V 0.131 0.188	ION: INCH.
STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR STYLE 6: PIN 1. GATE 2. EMITTER CASE: COLLECTOR	STYLE 2:         STYLE 3:           PIN 1. BASE         PIN 1. GATE           2. COLLECTOR         2. SOURCE           CASE: EMITTER         CASE: DRAIN           STYLE 7:         STYLE 8:           PIN 1. ANODE         PIN 1. CATHODE #1           2. OPEN         2. CATHODE #2           CASE: CATHODE         CASE: ANODE	STYLE 4: STYLE 5: PIN 1. GROUND 2. INPUT CASE: OUTPUT STYLE 9: PIN 1. ANODE #1 2. ANODE #2 CASE: CATHODE	E AL TRIP/DELAY

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